Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-537-9100

View Online at https://defobdaegroup.com/nai//3301-01-337-3100	
Inclosure Material:	
Metal	
Overall Length:	
Between 0.195 inches and 0.350 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inches and 0.265 inches	
Electrode Internally-electrically Connected To Case:	
Cathode	
Mounting Method:	
Terminal	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
10.0 regulator voltage	
Voltage Tolerance In Percent:	
-5.0/+5.0	
Current Rating Per Characteristic:	
25.00 milliamperes all primaries horsepower metric and 95.00 milliamperes repetitive peak forward current	
Power Rating Per Characteristic:	
1.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
175.0 degrees celsius ambient air	
Test Data Document:	
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification	n
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain	
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	

Demilitarization:

No

Fiig:

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